# TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS062B – Revised July 2003

### CMOS Binary Rate Multiplier

High-Voltage Types (20-Volt Rating)

■ CD4089B is a low-power 4-bit digital rate multiplier that provides an output pulse rate that is the clock-input-pulse rate multiplied by 1/16 times the binary input. For example, when the binary input number is 13, there will be 13 output pulses for every 16 input pulses. This device may be used in conjunction with an up/down counter and control logic used to perform arithmetic operations (adds, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigometric functions, A/D and D/A conversions, and frequency division.

For words of more than 4 bits, CD4089B devices may be cascaded in two different modes: an Add mode and a Multiply mode (see Figs.14 and 15). In the Add mode some of the gaps left by the more significant unit at the count of 15 are filled in by the less significant units. For example, when two units are cascaded in the Add mode and programmed to 11 and 13, respectively, the more significant unit will have 11 output pulses for every 16 input pulses and the other unit will have 13 output pulses for every 256 input pulses for a total of

<u>11 13 189</u> 16 256 256

In the Multiply mode the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second multiplier. Thus the output rate will be 11, 13, 143

16 16 256

#### Features:

- Cascadable in multiples of 4-bits
- Set to "15" input and "15" detect output
- = 100% tested for guescent current at 20 V
- = 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) =

1 V at  $V_{DD} = 5 V$ 2 V at  $V_{DD} = 10 V$ 2.5 V at  $V_{DD} = 15 V$ 

Meets all requirements of JEDEC Tentative Standard No. 138, "Standard

Specifications for Description of 'B' Series CMOS Devices''

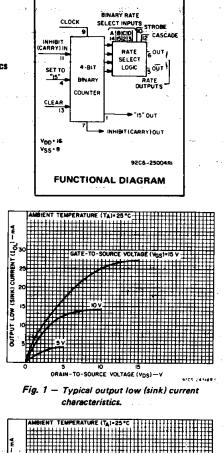
#### Applications:

- Numerical control
- Instrumentation
- Digital filtering
- Frequency synthesis

The CD4089B has an internal synchronous 4-bit counter which, together with one of the four binary input bits, produces pulse trains as shown in Fig. 2.

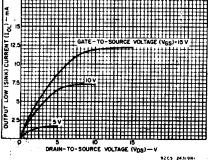
If more than one binary input bit is high, the resulting pulse train is a combination of the separate pulse trains as shown in Fig. 2.

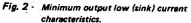
The CD4089B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).



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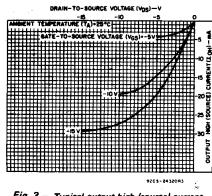


Fig. 3 — Typical output high (source) current characteristics.

CD4089B Types



**RECOMMENDED OPERATING CONDITIONS at T<sub>A</sub> = 25°C, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:** 

CHARACTERISTIC		V <sub>DD</sub>	LIŇ	UNITS	
		(V)	Min.	Max.	
Supply-Voltage Range (For T <sub>A</sub> Temperature Range)		3	18	V	
Set or Clear Pulse Width,	tw	5 10 15	160 90 60	- - -	ns
Clock Pulse Width,	tw	5 10 15	330 170 100	-	ns
Clock Frequency,	<sup>f</sup> CL	5 10 15	dc	1.2 2.5 3.5	MHz
Clock Rise or Fall Time,	trCL or tfCL	5, 10,15	-	15	μs
Inhibit In Setup Time,	ts∪	5 10 15	100 40 20	·	ns
Inhibit In Removal Time,	<sup>t</sup> REM	5 10 15	240 130 110	_ <u>_ </u> > ^	ns
Set Removal Time,	tREM	5 10 15	150 80 50		ns
Clear Removal Time,	<sup>t</sup> REM	5 10 15	60 40 30	_ _ _	ns

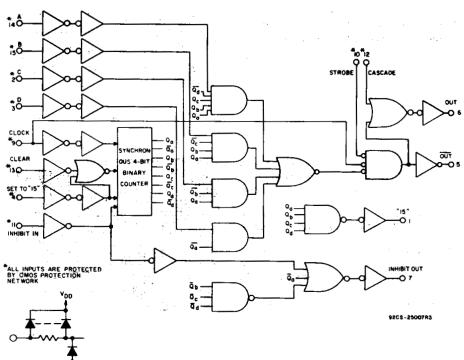


Fig. 4 — Logic diagram.

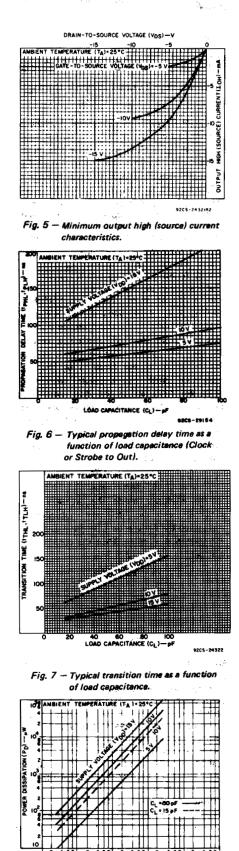


Fig. 8 – Typical dynamic power dissipation as a function of input frequency.

#### DYNAMIC ELECTRICAL CHARACTERISTICS at T<sub>A</sub> = 25°C; Input t<sub>r</sub>, t<sub>f</sub> = 20 ns, C<sub>L</sub> = 50 pF, R<sub>1</sub> = 200 k $\Omega$

CHARACTERISTIC	TES CONDIT					UNITS
		VDD	<u> </u>	LIMITS		01113
		v	Min.	Тур.	Max.	[
Propagation Delay Time, tpHL, tpLH		5	_	110	220	
Clock to Out		10	-	55	110	
		15		45	90	ns
		5	-	150	300	
Clock or Strobe to Out		10	-	75	150	
·		15	-	60	120	
Clock to Inhibit Out		5	-	360	720	
High Level to Low Level		10	-	160	320	ns
<u> </u>		15		110	220	
Low doubte High Lowel		5	-	250	500	
Low Level to High Level		10 15		100	200	ns
				75	150	
Clear to Out		5 10	-	380	760	
		15	_	175 130	350 260	ns
	<u> </u>	5				
Clock to "9" or "15" Out		10	_	300 125	600 250	ns
		15	_	90	180	113
·····		5	_	90	180	
Cascade to Out		10		45	90	ns
		15	_	35	70	
		5	-	160	320	
Inhibit In to Inhibit Out		10	_	75	150	
		15	-	55	110	กร
		5	_	330	660	113
Set to Out		10	-	150	300	
		15		110	220	
		5	- 1	100	200	
Transition Time, <sup>t</sup> THL <sup>, t</sup> TLH	÷.	10	-	50	100	ns
		15	-	40	80	
		5	1.2	2.4	- 1	
Maximum Clock Frequency, f <sub>CL</sub>		10	2.5	5	-	MHz
		15	3.5	7		
		5	-	165	330	
Minimum Clock Pulse Width, t <sub>W</sub>		10	- ,	85	170	ns
		15		50	100	
Clock Rise or Fall Time, t <sub>rCL</sub> , t <sub>fCL</sub>		5	-	-	15	
Clock Rise or Fall Time, t <sub>rCL</sub> , t <sub>fCL</sub>		10 15			15 15	μs
Minimum Set or Clear Pulse Width, tw	1	5 10		80 45	160 90	ns
		15	_	45 30	60	
		5		50	100	
Minimum Inhibit-In Setup Time, t <sub>SU</sub>		5 10		50 20	40	ns
		15	_	10	20	
		5	_	120	240	<u> </u>
Minimum Inhibit In		10	_	65	130	ns
Removal Time, <sup>t</sup> REM	:	15	_	55	110	

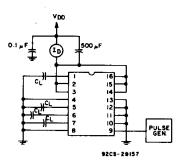


Fig. 9 - Dynamic power dissipation test circuit.

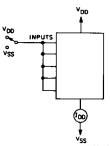


Fig. 10 - Quiescent device current test circuit.

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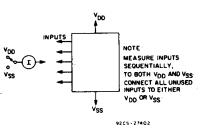


Fig. 11 - Input-current test circuit.

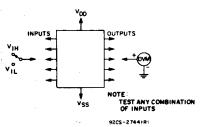
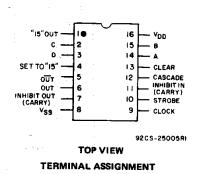


Fig. 12 - Input-voltage test circuit.



CHARACTERISTIC	TEST CONDITIO	NS		UNITS			
		VDD		LIMITS			
	. ÷	v	Min.	Тур. Мах.			
		5	·	75	150		
Minimum Set Removal Time, tRE	м	10	-	40	80	ns	
		15	— ·	25	50		
		5		30	60		
Minimum Clear Removal Time, tR	EM	10		20	40	ns	
		15		. 15	30		
Input Capacitance, CI	Any Input	-	:- "	5	7.5	pF	

# DYNAMIC ELECTRICAL CHARACTERISTICS at T<sub>A</sub> = 25°C (cont'd) Input t<sub>r</sub>, t<sub>f</sub> = 20 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 200 k $\Omega$

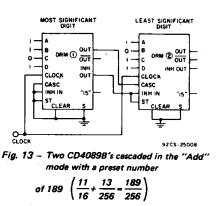
#### STATIC ELECTRICAL CHARACTERISTICS

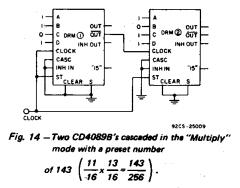
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CHARAC- TERISTIC	CON	DITIO	NS	L.IN	LIMITS AT INDICATED TEMPERATURES (°C)									
	V <sub>0</sub> (V)	V <sub>IN</sub> (V)		55	40	+85	+125	Min.	+25 Typ.	Max.	S			
	_	0,5	5	5	5	150	150		0.04	5				
Quiescent Device	_	0,10	10	10	10	300	300	_	0.04	10	μA			
Current,	_	0,15	15	20	20	600	600		0.04	20	μΑ			
IDD Max.	-	0,20	20	100	. 100	3000	3000	-	0.08	100				
Output Law	0.4	0,5	5	0.64	0.61	0.42	0:36	0.51	1	-				
Output Low (Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6					
OL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-	mA			
Outras Link	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-				
Output High (Source)	2.5	0,5	5	2	-1.8	-1.3	-1.15	-1.6	-3.2	_				
Current,	9.5	0,10	10	- 1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-				
<sup>1</sup> OH <sup>Min.</sup>	13.5	0,15	15	-4.2	-4	-2.8	- 2.4	-3.4	-6.8					
Output Voltage:	_	0,5	5		0	.05		- 0 0.0						
Low-Level,	-	0,10	10		0	.05			0	0.05	.05			
VOL Max.	-	0,15	15		0	.05		-	0	0.05	l v			
Output	-	0,5	5		4	.95		4.95	5	_				
Voltage	-	0,10	10		9	.95		9.95	10	-	1			
High-Level, VOH <sup>Min.</sup>	-	0,15	15		14	.95		14.95	15	-	1			
	0.5,4.5	-	5			1.5		-	-	1.5				
Input Low Voltage	1,9	_	10	•		3		-		3	1			
VIL Max.	1.5,13.5	-	15			4		-	-	4	۱ <sub>v</sub>			
Input High	0.5,4.5		5			3.5		3.5	. –	-				
Voltage,	1,9	·	10			7		7	-	-				
V <sub>IH</sub> Min.	1.5,13.5	_	15			11		11	-	-	1			
Input Current		0,18	18.	±0.1	±0.1	±1	±1.	. –	±10-5	±0.1	μ			

. ...

							IRU	JTH TA	BLE				
							OUTPL	ITS					
			1	nput	er of Pu Logic L ow; 1 =			0	umber of utput Log = Low; F	ic Level	Ì		
D	С	В	A	CLK	INH IN	STR	CAS	CLR	SET	OUT	OUT	INH OUT	"15" OUT
0	0	0	0	16	0	0	0	0	0	L	н	1	1
0	0	0	1	16	0	0	0	0	0.	1	1	1	1
0	0	1	0	16	0	0	0	0	0	2	2	1	1.
0	0	1	1	16	0	0	0	0	0	- 3	. 3	1.	1
0	1	0	0	16	0	0	0	0	0	4	4	1	1
0	1	0	1	16	0	0	0	0	0	5	5	1	1
0	1	1	0	16	0	0	0	0	0	6	6	1	1
0	1	1	1	16	0	0	0	0	0	7	7	1	1
1	0	0	0	16	0	0	0	0	0	8	8	1	1
1	0	0	1	16	0	0	0	0	0	9	9	1	1
1	0	1	0	16	0	. 0	0	0	0	10	10	1	1
1	0	1	1	16	0	0	0	0	0	11	11	. 1	1
1	1	0	0	16	0	• 0	0	0	0	12	12	1	1
1	1	0	1	16	0	0	0	0	0	13	13	1	1
1	1	1	0	16	0	0	0	0	0	14	14	1	1
1	1	1	1	16	0	0	0	0	0	15	15	1	1
x	x	x	x	16	1	0	~ 0	0	0	t	t	н	+
x	х	х	X	16	0	1	0	0	0	ι	н	1	1
X	х	х	х	16	0	0	1	0	0	Ĥ	*	1	1
1	х	х	х	16	0	0	0	1	0	16	16	н	L
0	х	х	X	16	0	0	0	1	0	L	н	н	L
X	Х	Х	X	16	0	0	0	X	1	L	н	L	н



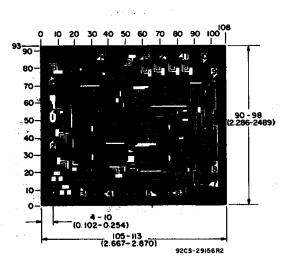


COMMERCIAL CMOS HIGH VOLTAGE ICS

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\* Output same as the first 16 lines of this truth table (depending on values of A, B, C, D).

<sup>†</sup> Depends on internal state of counter.



Dimensions and Pad Layout for CD4089BH

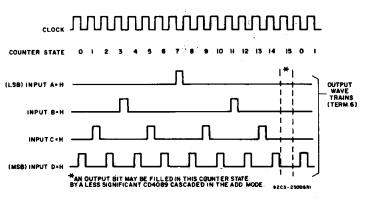


Fig. 15 - Timing diagram.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils  $(10^{-3} \text{ inch})$ .

3-213



#### PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	-	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
CD4089BE	ACTIVE	PDIP	N	16	25	RoHS & Green		N / A for Pkg Type	-55 to 125	CD4089BE	Samples
CD4089BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4089BE	Samples
CD4089BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4089B	Samples
CD4089BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM089B	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All	dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	CD4089BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
	CD4089BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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### PACKAGE MATERIALS INFORMATION

17-Dec-2020



\*All dimensions are nominal

Device	evice Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD4089BNSR	SO	NS	16	2000	853.0	449.0	35.0	
CD4089BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0	

### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



# **PW0016A**



## **PACKAGE OUTLINE**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



## PW0016A

# **EXAMPLE BOARD LAYOUT**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## PW0016A

# **EXAMPLE STENCIL DESIGN**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

#### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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